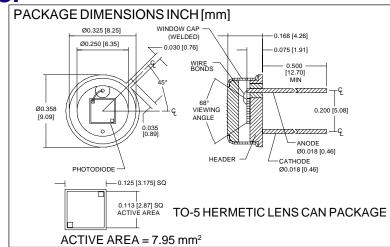
PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive DETECTORS INC. Type PDB-C119





FEATURES

- Wide view angle
- High speed
- Large active area
- Low dark current

DESCRIPTION

The **PDB-C119** is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-5 metal can with a glass window cap.

APPLICATIONS

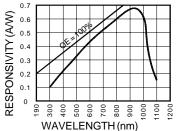
- Bar code detector
- Encoder sensor
- Laser detection
- Instrumentation

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		100	V
T _{STG}	Storage Temperature	-55	+150	∘C
То	Operating Temperature Range	-40	+125	∘C
Ts	Soldering Temperature*		+240	∘C
IL	Light Current		0.5	mA

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

(// 20 0 // 10 // 20 0 // 10 // 20 0 // 10								
SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS		
Isc	Short Circuit Current	H = 100 fc, 2850 K	90	110		μ A		
ΙD	Dark Current	H = 0, V _R = 10 V		5	20	nA		
Rsн	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$	150	300		MΩ		
TC RsH	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-8		%/℃		
Cı	Junction Capacitance	H = 0, V _R = 10 V**		60	150	pF		
λrange	Spectral Application Range	Spot Scan	350		1100	nm		
λр	Spectral Response - Peak	Spot Scan		950		nm		
VBR	Breakdown Voltage	I = 10 μA	75	100		V		
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		5x10 ⁻¹⁴		W/ √ Hz		
tr	Response Time	$RL = 1 K\Omega V_a = 10 V$		50		nS		

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.**f=1 MHz